



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Noboru ICHINOSE, et al.

Serial No.: 10/589,852

Group Art Unit: 2829

Filing Date: November 27, 2006

Examiner: Daniel B. Whalen

For: METHOD FOR CONTROLLING CONDUCTIVITY OF Ga_2O_3 SINGLE CRYSTAL

Honorable Commissioner of Patents
Alexandria, Virginia 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

Under the provisions of 37 CFR §1.97 through §1.98 and pursuant to Applicant's duty of disclosure under 37 CFR §1.56, Applicant respectfully brings the following Japanese Office Action to the attention of the Examiner in charge of the above-identified application.

In compliance with the concise explanation requirement under 37 CFR §1.98(a)(3) for foreign language documents, Applicant encloses herewith a copy of the Japanese Office Action, together with an English-language version (if not already included) of that portion of the Office Action indicating the degree of relevance found by the foreign office.

I hereby certify that each item of information contained in this Information Disclosure Statement was the first citation of that item by a foreign patent office in a counterpart foreign application, which occurred not more than three months prior to the filing of this statement.

It is respectfully requested that the Japanese Office Action be considered by the Examiner and formally made of record in this application.

U.S. Application Serial No.: 10/589,852
PKHF-05004US
(HIR.228)

Please charge any deficiencies in fees and credit any overpayment of fees to
Attorney's Deposit Account No. 50-0481.

Respectfully submitted,



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